# **3A Synchronous Buck Converter with I2C Interface**

## **General Description**

The ET8330 is a synchronous BUCK converter with I<sup>2</sup>C interface. The output voltage and dynamic voltage scaling (DVS) slew rate can both be programmed by I<sup>2</sup>C.

When the load is moderate and heavy, the converter operates in PWM mode with 2.4MHz quasi fixed frequency. In light load condition, it can work in pulse frequency modulation (PFM) mode to achieve high efficiency by setting VSEL pin to low. In PFM mode, the typical quiescent current is only about 30uA. Even with such low quiescent current, the load transient performance is still excellent, due to adaptive constant on time (ACOT) structure has been adopted in ET8330.

When VSEL PIN is set to high, it always works in PWM mode, no matter what the load is. In Shutdown Mode, the supply current is typically about 0.2uA.

The ET8330 is available in a small WLCSP15 (1.15mm x1.95mm).

### Features

- Programmable Output Voltage: 0.5V to 1.3V
- 2.5V to 5.5V Input Voltage Range
- Programmable Slew Rate for Dynamic Voltage Scaling (DVS)
- Quasi Fixed 2.4MHz Switching Frequency
- PFM Mode in Light Load Condition
- Excellent Load Transient Performance
- Capable of Delivering 3A Current
- 30uA Input Current with No Load in PFM Mode
- Thermal Shutdown and Over Current Protection
- WLCSP15 (1.15mm ×1.95mm ,0.4 pitch )Package

## Applications

- Application Processors
- Hard Disk Drives, LPDDR3, LPDDR4
- Tablets, Notebooks, Ultra-Mobile PCs
- Smart Phones
- Handheld Devices

# **Pin Configuration**



## **Pin Function**

Pin No.	Pin Name	Pin Function
A1, B1, C1	VIN	Power supply pins. Connect to CIN capacitor as close as possible.
A2, B2	SW	Switching pins. Connect to the inductor.
A3 B3 C2	PGND	Power ground pins. The low-side MOSFET is referenced to these pins. CIN
A3, B3, C2	FGND	and COUT should be returned with a minimum path to these pins.
C3,E1	AGND	Analog ground pins. All signals are referenced to this pin.
		FPWM or auto PFM/PWM select pin. When this pin is low, the converter
D1	VSEL	works in auto PFM/PWM mode. When this pin is high, it works in forced
		PWM mode.
D2	EN	Enable pin. The device is shutdown Mode when this pin is low.
D3	SDA	I <sup>2</sup> C serial data.
E2	SCL	I <sup>2</sup> C serial clock.
E3	VOUT	VOUT. Output voltage sense through this pin. Connect to output capacitor.

## **Block Diagram**



# Operation

## **General Descriptions**

The ET8330 is a synchronous step-down converter with 2.5V to 5.5V input voltage range. It's capable of delivering 3A current for output continuously. The output voltage ranges from 0.5V to 1.3V, which can be dynamically programmed by I2C. To achieve excellent transient performance, ACOT structure has been adopted. By using this structure it can easily keep loop stable even with low-ESR ceramic output capacitors.

In steady-state PWM operation, the feedback voltage is compared to voltage reference. When the feedback voltage is less than the reference voltage, the on-time one-shot is triggered and high side power FET is turned on. When the on-time is over, the high side power MOSFET is turned off and the low side power MOSFET is turned on, until feedback voltage is lower than voltage reference.

In auto PFM mode, the on-time of high side MOSFET is same as that in PWM mode. However, because of low load, it takes much longer time discharge the output voltage. So after on-time is over, the off-time of high side power MOSFET is much longer accordingly. Then the frequency decreases automatically.

## **PWM Frequency and Adaptive On-Time Control**

The on-time can be roughly calculated by the below equation:

$$T_{ON} = \frac{V_{OUT}}{V_{IN}} \times \frac{1}{f}$$

Where **f** is nominal 2.4MHz.

### **Zero Current Detector**

The zero current detector circuit senses the SW voltage during low side power MOSFET is on. When the SW voltage decreases to near zero, the low-side MOSFET is turned off to prevent the current flowing from output to GND.

### Under-Voltage Protection (UVLO)

The UVLO module continuously monitors input voltage to make sure the converter works properly. When the input voltage is higher than threshold voltage of UVLO, the converter begins soft start to its regulated output voltage. When the input voltage decreases to its low threshold (350mV hysteresis), the converter shuts down.

### Power GOOD

When the output voltage is higher than PGOOD rising threshold, 90% of its target voltage, the PGOOD flag is high.

#### **Output Under-Voltage Protection (UVP)**

When the output voltage is lower than 70% reference voltage after soft-start, the UVP is triggered.

## **Over-Current Protection (OCP)**

When the low side power MOSFET is on, the ET8330 senses the inductor current. Only when the current is smaller than limit value, the high side power MOSFET is possibly turned on, even though the feedback voltage is lower than voltage reference. If the OCP last for about 2ms, it enters into hiccup mode. In hiccup mode, the shut time is about 1.7ms

#### Soft-Start

An internal current source charges an internal capacitor to build the soft-start ramp voltage. The typical soft start time can be programming by I<sup>2</sup>C.

#### **Over-Temperature Protection (OTP)**

The ET8330 has over-temperature protection. When the junction temperature rises up to 150°C, it triggers OTP, and the device will be shut down, until junction temperature falls to 120°C.

## Absolute Maximum Ratings

Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Symbol	Parameter	Rating	Unit	
V <sub>IN</sub>	Supply Input Voltag	ge	-0.3 to 7	V
Vsw	SW Pin Switch Volta	age	-1 to 7.3	V
V <sub>SW_MAX</sub>	Switch Voltage<50	ns	-5 to 8.5	V
V <sub>IO</sub>	Other I/O Pin Voltag	-0.3 to 7.3	V	
PD	Power Dissipation@ T <sub>A</sub> = 25°C	WLCSP15	2.38	W
θ <sub>JA</sub> (1)	Package Thermal Resistance	42	°C/W	
Тјмах	Junction Temperate	ure	150	°C
T <sub>STG</sub>	Storage Temperatu	-65 to 150	°C	
TL	Lead Temperature (Soldering	260	°C	
ESD	HBM (Human Body Mc	odel) <sup>(2)</sup>	2000	V

*Note* **1**:  $\theta_{JA}$  is measured under natural convection (still air) at  $T_A = 25^{\circ}$  C with the component mounted on a high effective-thermal-conductivity four-layer test board on a JEDEC 51-7 thermal measurement standard.

*Note 2*: Devices are ESD sensitive. Handling precaution recommended.

## **Recommended Operating Range**

The device is not guaranteed to function outside its operating conditions.

Symbol	Item	Rating	Unit
VIN	Supply Input Voltage	2.5 to 5.5	V
Іоит	Output Current	0 to 3	А
TJ	Junction Temperature	-40 to 125	°C
T <sub>A</sub>	Ambient Temperature	-40 to 85	°C

# **Electrical Characteristics**

 $V_{\text{IN}}\text{=}$  3.6V,  $T_{\text{A}}\text{=}$  -40°C to 85°C, unless otherwise specified.

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Operating Quiescent Current PWM		I <sub>Q_PWM</sub>	$I_{LOAD} = 0$ , mode Bit = 1 (Forced PWM) <sup>(3)</sup>		11		mA
Operating Curren	Quiescent t PFM	I <sub>Q_PFM</sub>	I <sub>LOAD</sub> = 0		30		μA
H/W Sh Supply	utdown Current	Ishdn_h/w	EN = GND		0.2	3	μA
S/W Sh Supply	utdown Current	I <sub>SHDN_S/W</sub>	$EN = V_{IN}, BUCK\_ENx = 0,$ $2.5 V \le V_{IN} \le 5.0 V$		2	12	μA
Under-Volta Thres	ge Lockout shold	Vuvlo	VIN rising		2.32	2.45	V
Under-Volta Hyste	ge Lockout eresis	$ riangle V_{UVLO}$			350		mV
RDS(ON) O	f P-MOS	RDS(ON)_P	V <sub>IN</sub> = 5V		27		mΩ
R <sub>DS(ON)</sub> of N	I-MOSFET	R <sub>DS(ON)_L</sub>	V <sub>IN</sub> = 5V		16		mΩ
Input Voltago	Logic-High	VIH	$2.5 \text{ V} \le \text{V}_{\text{IN}} \le 5.0 \text{ V}$	1.1			V
Logic-Low		VIL	$2.5 \text{ V} \le \text{V}_{\text{IN}} \le 5.0 \text{ V}$			0.4	v
EN Input Bi	as Current	I <sub>EN</sub>	EN input tied to GND or $V_{\mbox{\scriptsize IN}}$		0.01	1	uA
V <sub>OUT</sub> DC Accuracy		∆Vout1	$2.8V \le V_{IN} \le 4.8V$ , $V_{OUT}$ from Minimum to Maximum, $I_{OUT(DC)} = 0$ to 3A, $V_{OUT} > 0.6V$ , Auto PFM/PWM <sup>(3)</sup>	-2		2	%
		∆Vout2	2.8V ≤ V <sub>IN</sub> ≤ 4.8V, V <sub>OUT</sub> from Minimum to Maximum, I <sub>OUT(DC)</sub> = 0 to 3A, V <sub>OUT</sub> ≤0.6V, Auto PFM/PWM <sup>(3)</sup>	-18		18	mV
		∆Ѵѹтз	2.8V ≤VIN≤ 4.8V, Vou⊤ from Minimum to Maximum, IouT(DC) = 0 to 3A, VouT>0.6V, Force PWM(Note3)	-2		2	%
		∆Vout4	2.8V ≤V <sub>IN</sub> ≤ 4.8V, V <sub>OUT</sub> from Minimum to Maximum, I <sub>OUT(DC)</sub> = 0 to 3A, V <sub>OUT</sub> ≤ 0.6V, Force PWM <sup>(3)</sup>	-12		12	mV
Load Re	gulation	$ riangle V_{LOAD}$	$I_{OUT(DC)} = 1 \text{ to } 3A^{(3)}$		0.10		%/A
Line Reg	gulation		$2.5V \le V_{IN} \le 5.0V$ , I <sub>OUT(DC)</sub> = 1.5A <sup>(3)</sup>		0.10		%/V

# **Electrical Characteristics (Continued)**

 $V_{\text{IN}}\text{=}$  3.6V,  $T_{\text{A}}\text{=}$  -40°C to 85°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Мах	Unit
		I <sub>LOAD</sub> step 0.01A to 1.5A,				
	AC <sub>LOAD1</sub>	$t_{R} = t_{F} = 500 ns,$		±45		mV
Transient Load Deenenee		V <sub>OUT</sub> = 1.125V <sup>(3)</sup>				
Transient Load Response		ILOAD step 0.1A to 1.8A,				
	ACLOAD2	$t_{R} = t_{F} = 1us, V_{IN} = 3.8V,$		±56		mV
		$V_{OUT} = 0.9 V^{(3)}$				
Transient Load Rosponse		I <sub>LOAD</sub> step 0.01A to 0.8A,				
Transient Load Response	ACLOAD3	t <sub>R</sub> = t <sub>F</sub> = 1µs, L = 0.33µH,		45		mV
		С <sub>оит</sub> = 22µF x 2 <sup>(3)</sup>				
		V <sub>IN</sub> = 3V to 3.6V,				
Line Transient	VLINE	t <sub>R</sub> = t <sub>F</sub> = 10us, I <sub>OUT</sub> = 100mA,		±40		mV
		Forced PWM mode <sup>(3)</sup>				
Valley Current Limit			3.5	4	4.5	А
Thermal Shutdown	$T_{SD}$			150		°C
Thermal Shutdown	Tas Jura			30		°C
Hysteresis	TSD_HYS			30		
Switching Frequency	fsw	V <sub>OUT</sub> = 0.6V		2400		kHz
Minimum Off-Time	toff_min			170		ns
DAC Resolution	(3)			8		Bits
DAC Differential	(3)				0.5	
Nonlinearity					0.5	LOB

Note 3: Guaranteed by design.

## Typical Operating Characteristics

Unless otherwise specified, Auto PFM/PWM mode,  $V_{IN}$  = 3.6V,  $V_{EN}$  =  $V_{IN}$ ,  $T_A$  = 25°C; Circuit and components according to typical application circuit.





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## **Application Circuit**



## **Table 1 Recommended External Components**

Component	Value	Size	Vendor
	330 nH	2016	DFE201610E-R33M(muRata)
L	470 nH	2520	DFE252012F-R47M(muRata)
C <sub>1</sub>	10uF / 10V	0603	CL10A106KP8NNNC(SAMSUNG)
C <sub>2</sub>	100nF / 10V	0402	CL05B104KO5NNNC(SAMSUNG)
C <sub>3</sub>	3*22uF / 6.3V	0603	CL10A226MQ8NRNC(SAMSUNG)

## **Application Information**

#### **General Descriptions**

The typical application circuit is shown in the figure of Application Circuit. External components are recommended in table 1. The external components should be properly chosen in order to achieve desired performance.

### **Inductor Selection**

The current ripple of inductor is determined by input voltage, output voltage, operating frequency and the value of inductor, as shown in below equation:

$$\Delta I_{L} = \frac{V_{OUT}(1 - \frac{V_{OUT}}{V_{IN}})}{f * L}$$

In above equation, f is the operating frequency and L is the inductance. In order to reduce current ripple, the inductor value should be increased.

According to above equation, when VIN is the biggest, the current ripple is the biggest correspondingly. In general, the ripple current ranges from  $0.3 \times I_{MAX}$  to  $0.4 \times I_{MAX}$ . To make sure the current ripple is smaller than a specified maximum, the inductor value shouldn't be smaller than below value:

$$L = \frac{V_{OUT}(1 - \frac{V_{OUT}}{V_{IN}})}{f * \Delta I_{I}}$$

### Input and Output Capacitor Selection

In order to reduce voltage ripple of VIN pin when high side power MOSFET is turned on and off, low ESR input capacitor  $C_{IN}$ , is needed to bypass VIN pin.

To meet size or height requirements, several capacitors may also be put in parallel at VIN and VOUT pin. Ceramic capacitors with high voltage rating and low ESR are suitable for switching regulator applications. However, they can also have a high voltage coefficient and audible piezoelectric effects. So the capacitors for VIN pin should be 10V rate, and for  $V_{OUT}$  should be 6.3V rate. In order to reduce  $V_{OUT}$  ripple and get better load transient performance, 3×22uF or larger capacitors can be used for VOUT

## I<sup>2</sup>C Interface Function

By using I<sup>2</sup>C interface, the VOUT voltage, Dynamic Voltage Scaling (DVS) slew rate, Auto PFM/PSM or FCCM mode all can be set according to customer' s requirement.

The register of each function can be found from the following register map and it also explains how to use these function.

## **VOUT Selection**

The VOUT can be set from 0.5V to 1300mV with 5mV resolution.

The output voltage can be set by NSELx register bit and the output voltage is given by the following equation:

 $V_{OUT} = 0.5V + VSELx \times 5mV$ For example : if VSELx = 00111100 (60 decimal), then  $V_{OUT} = 0.5 + 60 \times 5mV$ = 0.5 + 0.3 = 0.8V. The ET8330 also has external VSEL pin to select VSEL1(0x01) or VSEL0(0x00).Pull VSEL to high is for VSEL1 and pull VSEL to low is for VSEL0.

Upon POR, VSEL0 and VSEL1 are reset to their default voltages.

#### Enable and Soft-Start

When the EN pin is LOW, almost all internal circuits are turned off, and the device consumes very little current. However, if VIN is higher than threshold of Power On Reset (POR),  $I^2C$  can also be written to or read from  $I^2C$  interface. The registers will be reset when  $V_{IN}$  is lower than POR threshold.

When EN pin is high, VOUT will ramp up at the chosen soft-start slew rate which is programmed in the CONTROL2 register ss\_sr[1:0] bit.

Raising EN while the vseln\_en(n=0,1) bit is HIGH activates the part and begins the soft-start cycle. For the ET8330, there is 3ms and 2ms delay time from EN HIGH to VOUT start soft-start separately.

### **Discharge Function**

In the CONTROL1 register outdische bit is set to 1 can let  $V_{OUT}$  discharge by internal resistor when converter shuts down. If setting to 0  $V_{OUT}$  will decrease depending on the loading. When EN pin set to low, the ET8330 will default turn on internal 11 $\Omega$  discharge resistor.

#### Slew Rate Setting

The slew rate of V<sub>OUT</sub> can be set, when VOUT changes between two voltage levels. In the CONTROL1 register up\_sr[2:0] bits can control up-speed when in the CONTROL2 register dn\_sr[1:0] can control down-speed. The default up\_sr[2:0] slew rate is 20mV/us and dn\_sr[1:0] slew rate is 5mV/us.

#### Force PWM Mode

In the CONTROL1 register mode\_vsel0 and mode\_vsel1 can decide converter is always at PWM mode or enters power saving mode at light load condition.

The default operation mode of mode\_vsel0 is auto PWM/PFM mode and mode\_vsel1 is Continuous PWM mode.

During output voltage is changed from high to low, the ET8330 will make transition operate at PWM mode and output voltage will decrease quickly.

## I<sup>2</sup>C Interface

#### **Bus Interface**

Baseband Processor can transmit data with ET8330 each other through SDA and SCL port. SDA and SCL composite bus interface, and a pull-up resistor to the power supply should be connected.

#### **Data Validity**

When the SCL signal is high, the data of SDA port is valid and stable. Only when the SCL signal is low, the level on the SDA port can be changed.

## Start (Re-start) and Stop Working Conditions

When the SCL signal is high, SDA signal from high to low represents start or re-start working conditions, while the SCL signal is high, SDA signal from low to high represents stop working conditions.

## Byte Format

Each byte of data line contains 8 bits, which contains an acknowledge bit. The first data is transmitted MSB.

## Acknowledge

During the writing mode, ET8330 will send a low level response signal with one period width to the SDA port. During the reading mode, ET8330 will not send response signal and the host will send a high response signal one period width to the SDA.



- ACK = Acknowledge
- MSB = Most Significant Bit
- S = Start Conditions RS = Restart Conditions P = Stop Conditions
- Restart: SDA-level turnover as expressed by the dashed line waveform

## 7bit Address for chips

Chip Name	7bit Address
ET8330	1010000b

Chip write address(A0H) W	/rite Reg start address	(00-08H)								
♦ w 1 0 1 0 0 0 0 0	x x x x a d	d r		Re	g Data					
	<b>↓</b>								1	]
Start Chip address ack	cmdadr	ack cmd0	ack	cmd1	ack		ack	cmdn	ack	Stop/Rs
	I <sup>2</sup> C Writ	ting Comn	hand Re	egister	(conti	inuous)				
Start = Start Condition	S									
Chip address = Write r	egister addre	ess =1010	000+0(	w)b						
Ack = Acknowledge										
Write Reg start addres	s byte = cmd	ladr(xxxx ·	+ REG'	s 4bit ao	ddr)					
Ack = Acknowledge										
Reg data 0 = cmd0(Co	ommand data	0)								
Ack = Acknowledge										
Reg data n = cmdn(Co	ommand data	in)								
Ack = Acknowledge										
Stop/Rs = Stop Condition/Restart Condition										



- Start = Start Conditions
- Chip address =Write register address=1010000+0(w)b
- Ack = Acknowledge
- Write Reg start address byte = cmdadr(xxxx + REG's 4bit addr)
- Ack = Acknowledge
- Reg data = cmd(Command data)
- Ack = Acknowledge
- Stop/Rs = Stop Condition/Restart Condition

#### I<sup>2</sup>C Reading Command Register Interface Protocol(continuous):

Chip write address(A0H) Write Reg start address(00-08H) Chip write address(A1H)						
1       0       1       0       0       0       0       1       Reg Data Output 0         A       A       A       A       A       A       A       A       A						
Start     Chip Address     ack     cmdadr     ack     Restart     Chip Address     ack     Dataout()     ack     mack     Dataout     nack     Stop/Rs						
I <sup>2</sup> C Reading Command Register(continuous)						
• Start = Start Conditions						
<ul> <li>Chip address = Write register address =1010000+0(w)b</li> </ul>						
• Ack = Acknowledge from ET8330						
<ul> <li>Write Reg start address byte = cmdadr (xxxx + REG's 4bit addr)</li> </ul>						
• Ack = Acknowledge from ET8330						
Restart = Restart condition						
<ul> <li>Chip address Read register address =1010000+1(r)b</li> </ul>						
• Ack = Acknowledge from ET8330						
<ul> <li>Dataout0 = Register data output 0</li> </ul>						
<ul> <li>Ack = Acknowledge from Host</li> </ul>						
•						
<ul> <li>Dataoutn = Register data output n</li> </ul>						
<ul> <li>Nack = No Acknowledge from Host</li> </ul>						
<ul> <li>Stop/Rs = Stop Condition/Restart Condition</li> </ul>						
I <sup>2</sup> C Reading Command Register Interface Protocol:						
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$						
Start         Chip Address         ack         cmdadr         ack         Restart         Chip Address         ack         Dataout         nack         Stop/Rs						

- Start = Start Conditions
- Chip address = Write register address = 1010000+0(w)b
- Ack = Acknowledge from ET8330
- Write Reg start address byte = cmdadr(xxxx + REG's 4bit addr)
- Ack = Acknowledge from ET8330
- Restart = Restart condition
- Chip address Read register address = 1010000+1(r)b
- Ack = Acknowledge from ET8330
- Dataout = Register data output
- Nack = No Acknowledge from Host
- Stop/Rs = Stop Condition/Restart Condition

I<sup>2</sup>C Reading Command Register

## **Register Map**

Addr	Name	Descirption							
0x00	VSEL0				v	sel0[7:0]			
0x01	VSEL1				v	sel1[7:0]			
0x02	CONTRL1	dischg		up_sr[2:0	)]	0	sw_reset	vsel1_mode	vsel0_mode
0x03	CHIPID		100000 chipid[1:0](01b)					:0](01b)	
0x04	VERID		000000 verid[1:0](00b)					0](00b)	
0×05	MONITED	power_	uvlo_	ovp_	buck_	buck_	reset_	chip_	buck_
0x05	WONTER	good	sta	sta	vpos	vneg	stat	ovt	status
0x06	CONTRL2	dn_sr[2:0]			0	ss_sr[1:0]		vsel1_en	vsel0_en
0x07	CONTRL3	00				buck_	_en_dly[5:0]		
0x08	CONTRL4	00				buck_	_dis_dly[5:0]		

## **Register description**

## • 0x00 VSEL0 Register---- Output Voltage Setting Register When VSEL Pin Connect Low Level. Default = 0x14

Output voltage range is from 0.5V to 1.3V, each step=5mV.

The register VSEL0 sets the voltage when VSEL=0, it has 161 steps,

shown as below table, the formula is VOUT =0.500V + [d\*5mV];

Output Voltage Set by vsel0[7:0]							
Dec	Binary	Output Voltage(V)					
0	0000000	0.500					
1	0000001	0.505					
2	0000010	0.510					
3	00000011	0.515					
4	00000100	0.520					
5	00000101	0.525					
20	00010100(default for ET8330)	0.600					
50	00110010	0.750					
125	01111101	1.125					
145	10010001	1.225					
160	1010000	1.300					
161~255	10100001~1111111	Reserved					

### • 0x01 VSEL1 Register---- Output Voltage Setting Register When VSEL Pin Connect High Level. Default = 0x14

Output voltage range is from 0.5V to 1.3V, each step=5mV. The register VSEL1 sets the voltage when VSEL=1, it has 161 steps, shown as below table, the formula is VOUT =0.500V + [d\*5mV];

Output Voltage Set by vsel1[7:0]							
Dec	Binary	Output Voltage(V)					
0	0000000	0.500					
1	0000001	0.505					
2	00000010	0.510					
3	00000011	0.515					
4	00000100	0.520					
5	00000101	0.525					
20	00010100(default for ET8330)	0.600					
50	00110010	0.750					
125	0111101	1.125					
145	10010001	1.225					
160	10100000	1.300					
161~255	10100001~1111111	Reserved					

#### • 0x02 CONTROL1 Register---- Control Register Default = 0x92

Bit	Name	Default	Туре		Description		
	outdischg	1	R/W	Output Discharge Enabl	ed/Disabled Control:		
7				0b:Disabled			
				1b:Enabled			
				Output Voltage rising E	VVS step setting control:		
			R/W	Register Value	DVS step		
	up_sr[2:0]	001		000	40mv/us		
				001	20mv/us		
				010	10mv/us		
6:4				011	5mv/us		
				100	2.5mv/us		
				101	1.25mv/us		
				110	0.625mv/us		
				111	0.3125mv/us		
3	Rev.	0	R	Reserved			

				Register Software Reset Control
2	sw_reset	0	R/W	1b:Reset
				0b:auto clear after reset
				Buck Mode Setting Control When VSEL Pin Connect High
	mode_vsel1	1	R/W	Level:
I				0b:Auto PWM/PFM conversion mode
				1b:Continuous PWM mode
				Buck Mode Setting Control When VSEL Pin Connect High
0	mode_vsel0	0	R/W	Level::
				0b:Auto PWM/PFM conversion mode
				1b:Continuous PWM mode

## • 0x03 CHIPID Register---- Indicates the Product ID. Default = 0x81

die\_id[1:0] Indicates the die ID. Read only.

Bit	Name	Default	Туре	Description
7:2	default	100000	R	Default
1:0	chipid	01	R	Chip Identity

### • 0x04 VERID Register---- Indicates the Die version ID. Default = 0x00

ver\_id[1:0] Indicates the die version ID. Read only.

Bit	Name	Default	Туре	Description
7:2	default	000000	R	Default
1:0	verid	00	R	Version Identity

## • 0x05 MONITER Register ----Buck Status Register. Default = 0x00

Bit	Name	Default	Туре	Description
				Buck Enabled and Soft-start Completed Status:
7	power_good	0	R	0b:not start
				1b:start
				VIN Under Voltage Status:
6	uvlo_sta	0	R	0b:not under voltage
				1b:under voltage
				VIN Over Voltage Status:
5	ovp_sta	0	R	0b:not over voltage
				1b:over voltage
				Voltage Posedge Progress Status:
4	buck_vpos	0	R	0b:not in progress
				1b:in progress
				Voltage Negedge Progress Status:
3	buck_vneg	0	R	0b:not in progress
				1b:in progress
				Software Restart Occurrence Status, Auto Clear:
2	reset_stat	0	R	0b:not occur
				1b:occured

				Over Temperature Status:
1	chip_ovt	0	R	0b:not over temperature
				1b:over temperature
				Buck Enabled/Disabled Status:
0	buck_status	0	R	0b:Disabled
				1b:Enabled

## • 0x06 CONTROL2 Register---- Control register Default = 0x63

Bit	Name	Default	Туре	Description		
				Output Voltage Falling	g DVS Step Setting Control:	
				Register Value	DVS step	
				000	40mv/us	
				001	20mv/us	
				010	10mv/us	
7:5	dn_sr[2:0]	011	R/W	011	5mv/us	
				100	2.5mv/us	
				101	1.25mv/us	
				110	0.625mv/us	
				111	0.3125mv/us	
4	Rev.	0	R	Reserved		
	ss_sr[1:0]			Soft-start Time Setting Control:		
		00	R/W	Register Value	Soft-start time	
				00	100us	
3:2				01	200us	
				10	400us	
				11	800us	
				BUCK Enabled/Disable	d Control When VSEL Pin Connect High	
1	en_vsel1	1	R/W			
				Duels Enabled		
				BUCK Enabled/Disable	a Control when VSEL Pin Connect High	
0	en_vsel0	1	R/W			
				Ub:Disabled		
				1b:Enabled		

## • 0x07 CONTROL3 Register----Buck Enable Delay Time Set Register

buck\_en\_dly[5:0] set the delay time of starting Buck after EN or en\_vseln sets(n=0,1)

Delay time ranging from 0 to 63ms, step=1ms

The register CONTROL3 set the delay time of starting BUCK after EN or en\_vseln sets(n=0,1), it has 64steps, shown as below table, the formula is delay time =  $d^*1ms$ ;

BUCK Enable Delay Time Set by buck_en_dly[5:0]							
Dec	Binary	Delay Time(ms)					
0	000000	0					
1	000001	1					
2	000010	2					
3	000011(default for ET8330)	3					
4	000100	4					
5	000101	5					
62	111110	62					
63	111111	63					

## • 0x08 CONTROL4 Register---- Buck Disable Delay Time Set Register

buck\_dis\_dly[5:0] set the delay time of stopping Buck after EN or en\_vseln sets(n=0,1) Delay time ranging from 0 to 63ms, step=1ms

The register CONTROL3 set the delay time of starting Buck after EN or en\_vseln sets(n=0,1), it has 64steps, shown as below table, the formula is delay time =  $d^{*1}ms$ ;

Buck Disable Delay Time Set by buck_dis_dly[5:0]							
Dec	Binary	Delay Time(ms)					
0	000000(default for ET8330)	0					
1	000001	1					
2	000010	2					
3	000011	3					
4	000100	4					
5	000101	5					
62	111110	62					
63	111111	63					

## **Thermal Considerations**

The junction temperature should never exceed the absolute maximum junction temperature  $T_{J(MAX)}$ , listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula :

$$\mathsf{P}\mathsf{D}(\mathsf{MAX}) = \frac{(\mathsf{T}\mathsf{J}(\mathsf{MAX}) - \mathsf{T}\mathsf{A})}{\theta}\mathsf{J}\mathsf{A}$$

where  $T_{J(MAX)}$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction-to-ambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating Conditions is 125°C. The junction-to-ambient thermal resistance,  $\theta_{JA}$ , is highly package dependent. For a WLCSP15 1.15mm×1.95mm package, the thermal resistance,  $\theta_{JA}$ , is 42°C/W on a standard JEDEC 51-7 high effective-thermal-conductivity four-layer test board. The maximum power dissipation at  $T_A = 25^{\circ}C$  can be calculated as below :

 $P_{D(MAX)}$ = (125° C-25° C) / (42° C/W) = 2.38W for a WLCSP15 1.15mm×1.95mm package.

The maximum power dissipation depends on the operating ambient temperature for the fixed  $T_{J(MAX)}$  and the thermal resistance,  $\theta_{JA}$ . The derating curves in below Figure allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.



## Layout Considerations

For best performance of the ET8330, the following layout guidelines must be strictly followed.

- Input capacitor must be placed as close as possible to IC to minimize the power loop area. A typical 0.1uF decouple capacitor is recommended to reduce power loop area and any high frequency component on V<sub>IN</sub>.
- SW node is with high frequency voltage swing and should be kept at small area. Keep analog components away from the SW node to prevent stray capacitive noise pickup.
- Keep every power trace connected to pin as wide as possible for improving thermal dissipation.
- The AGND pin is suggested to connect to 2<sup>nd</sup> GND plate through top to 2<sup>nd</sup> via.



# Package Dimension



# **Tape Information**



# Marking



# **Revision History and Checking Table**

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2021-6-7	Initial Version	Xielh	Xielh	Zhujl
1.1	2021-10-12	Update Package Dimension	Xielh	Xielh	Zhujl
1.2	2021-11-8	Update V <sub>OUT</sub> vs Temperature graph	Xielh	Xielh	Zhujl
1.3	2023-1-31	Update Typeset	Shibo	Wum	Liujy